

W1131DT HIGH EFFICIENCY RED

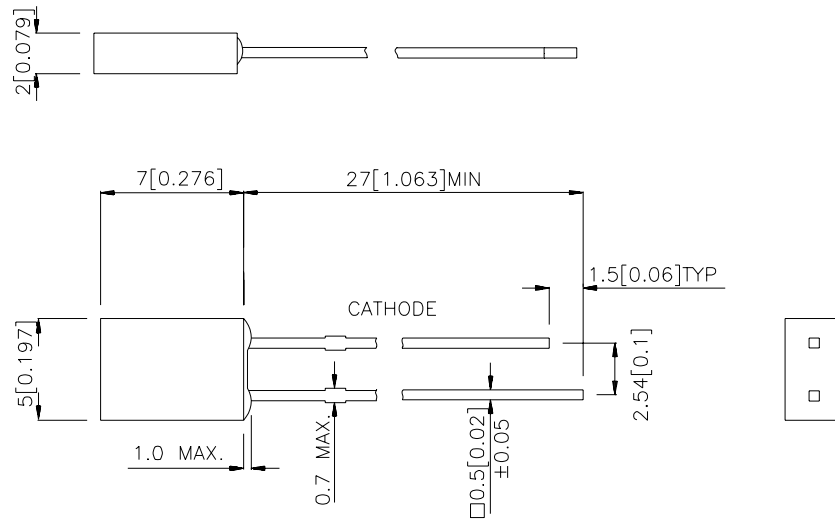
### Features

- LOW POWER CONSUMPTION.
- RELIABLE AND RUGGED.
- EXCELLENT UNIFORMITY OF LIGHT OUTPUT.
- SUITABLE FOR LEVEL INDICATOR.
- LONG LIFE - SOLID STATE RELIABILITY.

### Description

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

### Package Dimensions



#### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is  $\pm 0.25 (0.01)$  unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

## Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 10 mA		Viewing Angle
			Min.	Typ.	2θ1/2
W113IDT	HIGH EFFICIENCY RED(GaAsP/GaP)	RED DIFFUSED	3	5	110 °

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

## Electrical / Optical Characteristics at T<sub>A</sub>=25°C

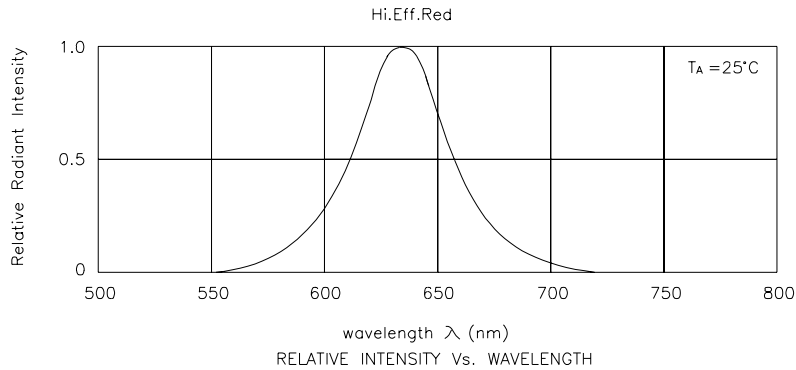
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ <sub>peak</sub>	Peak Wavelength	High Efficiency Red	627		nm	I <sub>F</sub> =20mA
λ <sub>D</sub>	Dominate Wavelength	High Efficiency Red	625		nm	I <sub>F</sub> =20mA
Δλ <sub>1/2</sub>	Spectral Line Half-width	High Efficiency Red	45		nm	I <sub>F</sub> =20mA
C	Capacitance	High Efficiency Red	15		pF	V <sub>F</sub> =0V;f=1MHz
V <sub>F</sub>	Forward Voltage	High Efficiency Red	2.0	2.5	V	I <sub>F</sub> =20mA
I <sub>R</sub>	Reverse Current	High Efficiency Red		10	μA	V <sub>R</sub> = 5V

## Absolute Maximum Ratings at T<sub>A</sub>=25°C

Parameter	High Efficiency Red	Units
Power dissipation	105	mW
DC Forward Current	30	mA
Peak Forward Current [1]	160	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 5 Seconds	

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.



## High Efficiency Red W1131DT

